

# HT9020B

# Call Progress Tone Detector

#### **Features**

• Operating voltage: 2.5V~5.5V

• Low power consumption

· Low cost 32768Hz crystal

• CPT Band: 305~640Hz detection

#### · Good performance:

 $-8 \sim -39$  dBm at  $V_{DD}$ =2.5V

 $0 \sim -27$  dBm at  $V_{DD}=5V$ 

• 8-pin DIP package

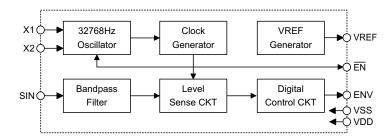
# **General Description**

The HT9020B call progress tone detector is a telecom peripheral for Auto-dialing system use.

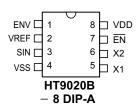
Switched capacitors technology is implemented into the chip to get good performance characteristics of band pass filter in the range of 305 to 640Hz call progress tone which is dual tone multi-frequency signal.

When it detected CPT signal then it generates relative envelopes for external microcontroller decision to finish different kinds of CPT signal detection such as dial tone, busy tone, ring-back tone and reorder tone.

## **Block Diagram**



## **Pin Assignment**

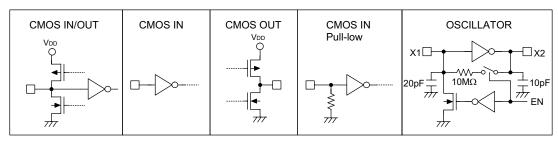




## **Pin Description**

Pin Name	I/O	Internal Connection	Description	
ENV	0	CMOS OUT	While an input signal is within specification, this pin will output the envelope relative to the input signal with a typical 40ms timing delay.	
VREF	0	CMOS OUT	1/2 V <sub>DD</sub> reference voltage output pin When EN=V <sub>DD</sub> , the device will be turned off and VREF disabled.	
SIN	I	CMOS IN	AC coupled analog signal input pin	
VSS	_	_	Negative power supply, ground	
VDD	_	_	Positive power supply	
EN	I	CMOS IN	EN=V <sub>SS</sub> ; Normal operation mode EN=V <sub>DD</sub> ; Device disabled.	
X1	I	OSCILLATOR	The system oscillator consists of an inverter, a bias resistor and the necessary on-chip load capacitor. Connect a standard 32.768kHz crystal or ceramic resonator.	
X2	0	OSCILLATOR	X1 and X2 terminals implement the oscillator function. The oscillator is turned off in the standby mode.	

## Approximate internal connection circuits



## **Absolute Maximum Ratings**

Supply VoltageV <sub>SS</sub> -0.3V to V <sub>DD</sub> +6V	Storage Temperature55°C to 150°C
Input VoltageV <sub>SS</sub> -0.3V to V <sub>DD</sub> +0.3V	Operating Temperature —20°C to 75°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.



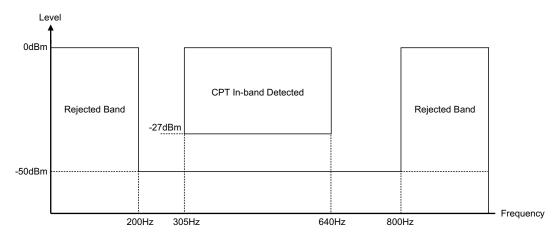
## **Electrical Characteristics**

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Symbol	Parameter	V <sub>DD</sub>	Conditions	Min.			
$V_{DD}$	Operating Voltage	_	_	2.5	_	5.5	V
	0	5V	Functions enabled	_	_	2	mA
I <sub>DD</sub>	Operating Current	2.5V	No load	_	_	0.8	mA
I <sub>STB</sub>	Standby Current	2.5V	Functions disabled or EN=1	_	_	1	μА
G <sub>DV</sub> D	Data dia da la cal	5V	f <sub>IN</sub> =305~640Hz	-36	_	0	dBm
	Detection Level	2.5V	ENV=1	-42	_	-8	dBm
G <sub>RL</sub>	Rejection Level	_	All frequency, ENV=0	_	_	-50	dBm
$f_{RL}$	Rejection Out-band	_	V≤0 dBm, ENV=0	_	_	200	Hz
f <sub>RH</sub>	Frequency			800	_	_	Hz
t <sub>Ql</sub>	Detection Pause Time		V <sub>SIN</sub> ≤ −50dBm, ENV=0	40	_	_	ms
$t_{DD}$	Detection Signal Time		In-band signal input, ENV=1	40	_	_	ms
t <sub>B</sub>	Rejection Pause Time	_	V <sub>SIN</sub> ≤ −50dBm, ENV=1	_	_	20	ms
t <sub>DH</sub>	Facility O dead Dales Time	_	Time for high output	_	40	_	ms
t <sub>DI</sub>	Envelope Output Delay Time	_	Time for low output	_	40	_	ms
t <sub>RD</sub>	Rejection Noise Time	_	V <sub>SIN</sub> =Any signal, ENV=0	_	_	20	ms
t <sub>ST</sub>	Oscillator Start-up Time		_	_	0.8	2	sec
Z <sub>I</sub>	Input Impedance f <sub>IN</sub> =200~3.4		f <sub>IN</sub> =200~3.4kHz	1.0	_	_	ΜΩ
V <sub>REF</sub>	Reference Voltage	_	No load	2.4	2.5	2.6	V
Z <sub>REF</sub>	Output Impedance		_	_	10	20	МΩ
V <sub>IH</sub>	Logic Input High Voltage		_	3.5	_	_	V
V <sub>IL</sub>	Logic Input Low Voltage		_	_	_	1.5	V
I <sub>IH</sub>	Logic Input High Current 5V		V <sub>IH</sub> =0.5V	_	_	0.1	μА
I <sub>IL</sub>	Logic Input Low Current 5V V <sub>IL</sub> =0V		V <sub>IL</sub> =0V	-0.1	_	_	μА
I <sub>OH</sub>	Output High Current	5V	V <sub>OH</sub> =4.5V	_	_	-0.5	mA
I <sub>OL</sub>	Output Low Current	5V	V <sub>OL</sub> =0.5V	2.0	_	_	mA
I <sub>SO</sub>	Pull-down Current		_	_	25	35	μА



## **Functional Description**

The HT9020B call progress tone detector can be used in world wide countries. Below is an illustration of a call progress tone frequency band, and a table of U.S.A. CPT signal is shown for user reference. Usually, HT9020B must work together with a microcontroller through software to distinguish correct cadence of CPT to fit any country CPT SPEC requirement for world wide application purposes.

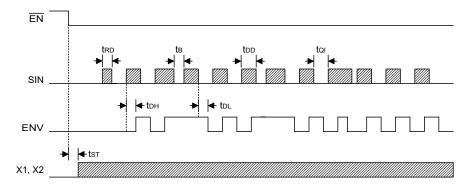


Call progress tone frequency band illustration

**U.S.A. Call Progress Tone Signal Format** 

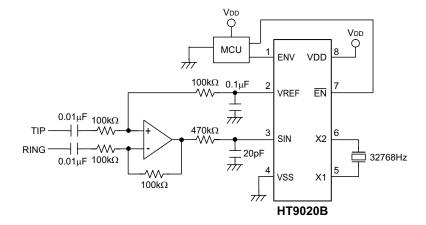
Tone	Frequency	Condition
Precision Dial Tone	350Hz+440Hz	Continuous high
Old Dial Tone	120Hz (or 133Hz,) +600Hz	Continuous high
Precision Busy Tone	480Hz+620Hz	0.5sec high and 0.5sec low
Old Busy Tone	120Hz+600Hz	0.5sec high and 0.5sec low
Precision Reorder Tone	480Hz+620Hz	0.3sec high and 0.2sec low
Old Reorder Tone	120Hz+600Hz	0.2sec high and 0.3sec low or 0.25sec high and 0.25sec low
Precision Ring-back Tone	440Hz+480Hz	2sec high and 4sec low
Old Ring-back Tone	40Hz (or the others) +420Hz	2sec high and 4sec low

## **Timing Diagram**





# **Application Circuits**





# **Package Information**

## 8-pin DIP (300mil) Outline Dimensions







Complete	Dimensions in mil					
Symbol	Min.	Nom.	Max.			
Α	355	_	375			
В	240	_	260			
С	125	_	135			
D	125	_	145			
E	16	_	20			
F	50	_	70			
G	_	100	_			
Н	295	_	315			
I	335	_	375			
α	0°	_	15°			



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